INFLUENCE OF THE SAMPLE MORPHOLOGY ON TOTAL REFLECTION X-RAY FLUORESCENCE ANALYSIS

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ABSTRACT

Total Reflection X-ray Fluorescence Analysis (TXRF) is a method for qualitative and quantitative analysis of trace elements. In general TXRF is known to allow for linear calibration typically using an internal standard for quantification. For small sample amounts (low ng region) the thin film approximation is valid neglecting absorption effects of the exciting and the detected radiation. However, for higher total amounts of samples deviations from the linear relation between fluorescence intensity and sample amount have been observed. The topic of the presented work is an investigation of the parameters influencing the absorption phenomenon. Samples with different total amounts of arsenic have been prepared to determine the upper limit of sample mass where the linear relation between fluorescence intensity and sample amount is no longer guaranteed. It was found that the relation between fluorescence intensity and sample amount is linear up to \textasciitilde100 ng arsenic. A simulation model was developed to calculate the influence of the absorption effects. Even though the results of the simulations are not satisfying yet it could be shown that one of the key parameters for the absorption effect is the density of the investigated element in the dried residues.

INTRODUCTION

Total Reflection X-ray Fluorescence analysis (TXRF) offers a nondestructive qualitative and quantitative analysis of trace elements and is extremely surface-sensitive. With TXRF the analysis of very small sample amounts is possible and the detection limits are in the pg-range (if the excitation source is an X-ray tube) [1-9]. In TXRF, absorption effects concerning exciting and detected radiation are usually disregarded. This is justified because mostly small sample amounts are used. The thin film approximation in particular assumes a very thin sample and therefore differential absorption for photons with different energies can be ignored. Furthermore the elements in the sample are assumed to be homogeneously distributed. Hence the loss of the fluorescence signal due to absorption of the primary beam equally affects all elements and quantification by using an internal standard is justified [10, 11]. For higher total amounts of samples deviations from the linear relation between fluorescence intensity and sample amount have been observed [12-14].

An investigation of the parameters influencing the absorption phenomenon is the content of the presented work. A simulation model was developed to calculate the influence of the absorption effects. Samples with different total amounts of arsenic were prepared to determine the upper limit of sample mass where the linear relation between fluorescence intensity and sample amount is no longer guaranteed. Furthermore the sample shapes on different reflector materials, as a
result of drying, were investigated (by analyses with a confocal white light microscope) as well as
the influence of the sample geometry on absorption effects.

EXPERIMENTAL

Preparation of the Samples
In this study we used a Si wafer, an acrylic glass reflector and quartz reflectors. They were
measured with TXRF (ATOMIKA EXTRA-IIA system, for experimental setup see “analytical
procedure”) and no contaminations were detected.
For the linearity test different amounts of arsenic (4 ng, 7 ng, 9 ng, 20 ng, 40 ng, 71 ng, 100 ng,
179 ng, 300 ng, 362 ng and 503 ng) were put on several quartz reflectors. An arsenic standard
solution was used (H$_3$AsO$_4$ in HNO$_3$, contains 1000mg/L arsenic, Producer: Merck). Using this
standard solution a dilution series with different concentrations of arsenic was prepared. One µL
of a specific solution of the dilution series was put on each reflector. The reflectors were weighed
to determine the effective arsenic amount (balance: SARTORIUS R300S, error: ±0.1mg) and
afterwards the samples were dried on a heating plate (temperature 100°C).

For the investigations of the influence of the sample shape on the fluorescence intensity 500 ng of
arsenic (solution: 500ppm, amount: 1µL) were put on two different reflector materials (Si wafer
and acrylic glass reflector). The preparation procedure was the same as described before except
for the drying procedure (drying in vacuum). The use of different reflector materials led to
different sample shapes. Vacuum drying is the more gentle drying procedure and since in this
case the influence of the reflector material on the sample shape was investigated, this method was
chosen to avoid a possible sample demolition by the drying procedure.

Analytical Procedure
TXRF analysis was performed using two different systems to guarantee reproducibility: the
ATOMIKA EXTRA-IIA system and the ATI TXRF vacuum chamber. The ATOMIKA EXTRA-
IIA system is equipped with a W and a Mo tube and a cut-off reflector. The measurements were
done in Mo Kα excitation mode at 1.27 mrad (angle of incidence), for 100 s live time, at 50kV.
The current was varied so that all measurements were done with the same dead time (40%).
The ATI TXRF vacuum chamber is equipped with a Mo tube and a multilayer monochromator.
The measurements were performed in Mo Kα excitation mode at 70% of the critical angle (∙=1.25
mrad) (angle of incidence), for 500 s live time, at 40kV and 10mA.

Confocal Microscopy
Measurements to determine the shape of the samples have been performed utilizing a confocal
white light microscope (NanoFocus µsurf® [15]). The analyses were done by the Austrian Center
of Competence for Tribology (AC2T [16]). The measuring field was ~1450 x 1400 µm with a
lateral resolution of ~1.5 x 1.5 µm and 50 nm in height. Due to the measurement setup it was
necessary to perform a plane correction. Furthermore speckles of questionable origin (traces of
the sample, measurement artifacts or contaminations) which were found on the quartz reflector
surfaces have been removed by using a threshold filter. The threshold filter removed each data
point with a height smaller than 10% of the maximum height of the sample. For further
investigations it is recommended to inspect the reflectors for speckles before applying the
samples. Figure 1 shows the 100 ng arsenic sample before and after the speckle correction.
THEORETICAL CONSIDERATIONS

A simulation model was developed to calculate the influence of the absorption effects. The model is applicable for the calculation of the fluorescence intensity emitted by a single-element sample in TXRF geometry. The base of the mathematical model is the formula for the calculation of the fluorescence intensity in XRF geometry given by Shiraiwa and Fujino [17] in the approximation for monoenergetic excitation.

The following assumptions for the calculation were made:
- The detector is assumed to be ideal and covers the whole solid angle. So the geometry factors can be ignored and the detector efficiency is $\varepsilon = 1$.
- The system is located in vacuum. Hence there is no absorption between tube and sample as well as sample and detector.
- The beam divergence is neglected.
- The fluorescence radiation is emitted perpendicular to the reflector surface.

To calculate the fluorescence intensity emitted by a sample of random shape in 2D the following approximation was made: any sample can be combined of $n$ variably high (height $h$) and variably broad (width $b$) towers (Figure 2).

![Fig. 2 Schematic illustration of the towers geometry (2D)](image)

The calculation of the fluorescence intensity is done for any tower separately considering the attenuation of the primary intensity by the preceding towers. Furthermore it is necessary to make
a case differentiation. There are three possible cases: the tower is hit by the beam (incident or reflected) completely (a), only partially (b) or not at all (c). The total intensity which is emitted by the whole sample results from a summation of the individual intensities.

To obtain the fluorescence intensity emitted by a 3-dimensional sample the intensity emitted by a tower is multiplied with its thickness.

The points of impact of the primary radiation are selected so that the whole sample is illuminated (Figure 3). That means that the footprint of the system is bigger than the sample.

To accomplish an accurate calculation it is necessary to know all the parameters given in the formula. The sample dimensions and the volume were determined by analyses with a confocal white light microscope. The density of arsenic in the sample \( \rho_{\text{real}} \) was estimated from its dimensions (volume \( V_S \)) and mass (\( m_S \)):

\[
\rho_{\text{real}} = \frac{m_S}{V_S}
\]

The values of the other fundamental parameters were obtained from databases [18-20].

RESULTS AND DISCUSSION

Linarity Test

Figure 4 shows the results of the linearity test. With the Extra IIA system the samples were measured two times, the second time the samples were 90° rotated. The determination of the count rate of arsenic was accomplished with QXAS [21]. To compare the curve shapes the intensities (cps/mA) obtained by the Extra IIA system were divided by 2.75. During the measurements it was found that the relation between fluorescence intensity and sample amount is linear up to ~100 ng arsenic. At larger sample amounts deviations from the linearity occurred.

The results of the measurements with the Extra IIA system show differences in the emitted intensities after rotating the samples. This could be caused either by a statistical error or an influence of the sample shape. The influence of the sample shape is discussed in the next part.

The measured fluorescence intensity emitted by the samples was compared to the calculated intensity (Figure 5) to test the linearity of the calculations and the measurements. For the comparison the curves were normalized. The mean value of the quotients of the measured and calculated values was chosen as the normalization factor.

However, the theoretical curve did not show the trend of the measured curve. Some of the difficulties for the simulation appear due to the determination of the density of arsenic in the sample. A possible error in the speckle correction could have led to a false value of the volume and hence of the density. Furthermore the samples don’t contain pure arsenic but arsenic oxide.
During the drying of the samples not all water is released [22]. This could affect the density calculation more than expected. The result of the calculation for the 300 ng arsenic sample is not shown because the value of the intensity is much too high. The extension in x- and y- direction of this sample is four times larger than the extensions of the other samples and this could have led to a higher value of the calculated intensity.

Comparison between ATI TXRF vacuum chamber and Extra II A system

Fig. 4 Linearity test

Comparison of Measurements and Calculations

Fig. 5 Comparison of measurements and calculations

Sample Shape
The same sample amount of arsenic was put on a Si wafer and an acrylic glass reflector to investigate the resulting specimen shape. The drying of the samples led to different sample shapes. The sample dimensions were obtained by analyses with the confocal white light microscope. Figure 6 shows the plot of sample on the acrylic glass reflector which has a ring shape. Figure 7 shows the plot of the sample on the Si wafer. This sample is not ring shaped but tower-like formations shaped.
A theory for the formation of a ring by solids dispersed in a drying droplet is described by Deegan et al. [23, 24]. According to this theory an outward flow within the droplet transports the solute to the contact line. (The contact line is the border where the surface of the droplet contacts the surface of the carrier). This flow occurs when the contact line is pinned so that liquid which is removed by evaporation from the edge of the drop must be refilled by a flow of liquid from the inside. The reasons for the contact line pinning are irregularities of the substrate: surface
roughness or chemical heterogeneity. Deegan et al. reported that no ring was formed when the pinning was eliminated by drying the drop on smooth Teflon. In this case the drying drop contracted as it dried. An expansion of the theory of Deegan was given by Popov [25] taking into account the volume occupied by the solute particles.

Referring to the theory proposed by Deegan and Popov the formation of the residues could be explained as follows: Some irregularity of the reflectors surface anchors the contact line of the deposited droplet at one or more points. As the liquid evaporates the solute particles are transported to these points and increase the pinning of the contact line. Eventually the primary droplet is disrupted to smaller droplets – one for each anchor point. Now these smaller droplets either undergo the same procedure again or contract at the anchor point. The shapes of the residues on the acrylic glass reflector and silicon reflector can be interpreted as antipodal extreme examples. The surface of the silicon reflector has a very small roughness and is highly hygroscopic. Therefore the contact line could be pinned only at a few points and almost the whole primary droplet contracted at one point. The acrylic glass reflector has a higher surface roughness and is less hygroscopic. Hence the whole contact line of the primary droplet is pinned at first. The solute particles are transported to the contact line and finally build a large number of small residues. Maybe this happens because they are themselves new anchor points.

**Influence of the Sample Geometry**

To investigate the influence of the sample geometry on absorption effects the fluorescence intensity emitted by the samples on the acrylic glass reflector and on the silicon reflector were measured and calculated. Though the samples have different shapes, they have the same extensions in x- and y-direction and hence the same base.

It was shown by both the calculation and the measurement that these differences of the sample shapes led only to minimal differing fluorescence intensities and hence that the influence of the sample shape for samples with the same base on the fluorescence intensity seems to be of less importance than expected. Assumption for the calculation: primary intensity $I_0=1$.

<table>
<thead>
<tr>
<th></th>
<th>$I/I_0$ (Calculation) [%] scaled to maximum</th>
<th>$I/I_0$ (Measurement) [%] scaled to maximum</th>
</tr>
</thead>
<tbody>
<tr>
<td>Si wafer</td>
<td>79</td>
<td>85</td>
</tr>
<tr>
<td>acrylic glass reflector</td>
<td>100</td>
<td>100</td>
</tr>
</tbody>
</table>

Table 1 Comparison of measured and calculated fluorescence intensities for different sample shapes

**CONCLUSIONS AND PERSPECTIVES**

Presumably one of the key parameters for the absorption effect is the density of the investigated element in the dried residues. For further investigations it is necessary to find a better possibility for determining the real density of the sample. For example the way of crystallizing of the solution should be regarded in density calculations and the use of reflectors which are tested for speckles before applying the samples is recommended to avoid subsequent corrections.

To confirm that the white light image is all based on the investigated element, µ-XRF measurements should be made to determine the actual elemental distribution.
Additionally the simulation model should be improved (e.g. consideration that the fluorescence intensity is emitted in all directions in space) and extended (to multi-element samples and other geometries), respectively.

Furthermore it was shown that the influence of the sample shape for samples with the same base on the fluorescence intensity seems to be of less importance. Now it has to be investigated if an influence of the sample geometry for samples with different extensions in x- and y-direction is negligible too. If the sample shape is influencing the intensity further investigations should include the following points:

- The sample preparation techniques have to be improved to obtain uniform dried spots. This would keep the influence of the sample geometry constant.
- The theoretically ideal TXRF specimen would be a thin, flat, homogeneous circle but especially at higher sample amounts it is almost impossible to produce. Further investigations will be done with picodroplet samples which match the ideal form well. In this case it is possible to produce samples consisting of a pattern of picodroplets so that the whole sample amount is distributed on many small almost ideal TXRF samples.

REFERENCES